**Supporting Information** 

## Temperature-dependent characteristics of n-channel transistors based

### on 5,5'-bithiazolidinylidene- 2,4,2',4'-tetrathiones

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### Synthesis

All commercial chemicals and solvents were used without further purification. Amylamine (A0445), and hexylamine (H0134) were obtained from TCI. Carbon disulfide (038-01246) was obtained from Wako. The data of Nuclear Magnetic Resonance spectrum (NMR) and Mass spectrum (MS) were obtained with a JEOL JNM-AL300 spectrometer and a JEOL JMS-Q1050GC mass spectrometer, respectively.



## 3,3'-Dimethyl-5,5'-bithiazolidinylidene-2,4,2',4'-tetrathione (SS-R).

Under nitrogen atmosphere, to a -10 °C cooled solution of *N*-alkyl-1,3-thiazole-2thione **1** (7.6 mmol)<sup>8</sup> in dry THF (50 ml) was added a solution of lithium diisopropylamide (LDA) freshly prepared from *n*-butyl lithium (*n*-BuLi) (11.5 mmol, 7.2 mL) and diisopropylamine (11.5 mmol, 1.6 mL) in 30 mL dry THF. After stirring for 30 min at -10 °C, S<sub>8</sub> (11.5 mmol, 366 mg) was added and the solution was stirred for additional 30 min. To the medium, a solution of LDA freshly prepared from n-BuLi (15.3 mmol, 9.6 mL) and diisopropylamine (15.3 mmol, 2.2 mL) in 30 mL dry THF was added. The reaction mixture was stirred at -10 °C for 3 h and sulfur S<sub>8</sub> (12.6 mmol, 403 mg) was added. After 30 min, triphosgene (11.4 mmol, 3.38 g) was added and stirred for 30 min at -10 °C and further stirred at room temperature overnight. The solution was evaporated *in vacuo* and extracted with dichloromethane and washed with water. The organic layer was dried over MgSO<sub>4</sub> and evaporated *in vacuo*. The crude product was purified by column chromatography using dichloromethane as eluent to afford **2** as a brown solid.

A solution of **2** in 50 mL toluene was refluxed overnight. 90% of the solution was evaporated in vacuo and the precipitate was filtered and washed with ethanol and dried in vacuo to afford **SS-***R* as a black solid. Crystals of sufficient quality for X-ray diffraction were obtained by slow evaporation of  $CH_2Cl_2$ .

**SS-Pen**: Yield: 45% (740 mg). <sup>1</sup>H NMR (300MHz, CDCl<sub>3</sub>)  $\delta$  0.98 (t, 3H, CH<sub>3</sub>, J = 7.4 Hz), 1.74 (m, 2H, CH<sub>2</sub>), 1.38 (m, 2H, CH<sub>2</sub>), 3.78 (m, 2H, CH<sub>2</sub>); HRMS (ASAP) calcd for C<sub>16</sub>H<sub>22</sub>N<sub>2</sub>S<sub>6</sub> [M + H]+: 434.776. Found: 434.8932; Anal. calcd for C<sub>16</sub>H<sub>22</sub>N<sub>2</sub>S<sub>6</sub>: C, 44.20; H, 5.10; N, 6.44. Found: C, 43.96; H, 4.87; N, 6.18.

**SS-Hex**: Yield 48% (840 mg). <sup>1</sup>H NMR (300MHz, CDCl<sub>3</sub>)  $\delta$  0.98 (t, 3H, CH<sub>3</sub>, J = 7.4 Hz), 1.78 (m, 2H, CH<sub>2</sub>), 1.35 (m, 2H, CH<sub>2</sub>), 3.88 (m, 2H, CH<sub>2</sub>); HRMS (ESI) calcd for C<sub>12</sub>H<sub>14</sub>N<sub>2</sub>S<sub>6</sub> [M + H]<sup>+</sup>: 462.828. Found: 462.9562; Anal. calcd for C<sub>18</sub>H<sub>26</sub>N<sub>2</sub>S<sub>6</sub>: C, 46.72; H, 5.66; N, 6.05. Found: C, 46.62; H, 5.46; N, 6.14.

#### Cyclic Voltammetry (CV) and ultraviolet-visible spectroscopy (UV-Vis)

Redox potentials were measured by cyclic voltammetry. Dry dichloromethane was used as a solvent,  $Bu_4N \cdot PF_6$  as an electrolyte and ALS-701E as a measuring instrument. An Ag/AgNO<sub>3</sub> electrode was used for the reference electrode, and glassy carbon and platinum electrodes were used for the working electrode and the auxiliary electrode, respectively.

Ultraviolet-visible absorption spectra were measured at room temperature using a quartz cuvette having a 1 cm path using a UV-1800 ultraviolet-visible spectrophotometer (Shimadzu). Dichloromethane was used as a solvent. With increasing the alkyl chain length, the splitting of the 500-600 nm peak became less important probably because it is related to the intermolecular interaction. The optical band gap (HOMO-LUMO gap) was calculated from the edge of the visible absorption band.

#### **Crystal Structures**

The X-ray oscillation photographs for **SS-Pen** were taken using a RIGAKU R-AXIS RAPID II imaging plate with Cu*K* $\alpha$  radiation from a rotation anode source with a confocal multilayer X-ray mirror (RIGAKU VM-Spider,  $\lambda = 1.54187$  Å). Diffraction data for **SS-Hex** were collected on a Rigaku AFC-7R four-circle diffractometer using MoK $\alpha$  radiation from a rotation anode source ( $\lambda = 0.71069$  Å). The structures were solved by the direct method (SHELXT) and refined by the full-matrix least-squares method by applying anisotropic temperature factors for all non-hydrogen atoms using the SHELXL programs.<sup>S1,S2</sup> The hydrogen atoms were placed at geometrically calculated positions. Transfer integrals were estimated from the overlap of the molecular orbitals.<sup>26</sup>



Figure S1. (a) Crystal structure of SS-Hex viewed along the molecular long axis.(b) Crystal structure of SS-Hex viewed along the *b* axis, and (b) along the *c* axis.

## Thin film properties

X-ray diffraction analyses of thin films (50 nm) on TTC (20 nm) were performed by X'pert-Pro-MRD using the  $\theta$ -2 $\theta$  technique with Cu-K $\alpha$  radiation for 2°  $\leq 2\theta \leq 20^{\circ}$ . AFM images of thin films (50 nm) on TTC (20 nm) were taken by a SII scanning probe microscope system SPI3800N and SPA-300 by using a Si<sub>3</sub>N<sub>4</sub> cantilever.

## **Transistor characteristics**



Figure S2. Transfer characteristics of an SS-Hex single-crystal transistor.



**Figure S3.** Output characteristics of single-crystal transistors measured at room temperature for (a) **SS-Pen** (//*b*), and (b) **SS-Hex** (//*b*).



Figure S4. Single-crystal transistors of (a) SS-Pr, (b) SS-Pen, and (c) SS-Hex.



**Figure S5.** (a) Summary of mobility. (b) Lattice co $V_3$  of **SS-Pr**.

(b) Lattice constants normalized by  $a_3 \sim c_3$  and



Figure S6. Arrhenius plots of  $I_D$  for transistors of (a) SS-Pr (//*a*), (b) SS-Pr (//*b*), (c) SS-Pen (//*b*), and (c) SS-Hex (//*b*).

# References

- S1 Sheldrick, G. M. SHELXT Integrated Space-Group and Crystal Structure Determination. *Acta Crystallogr. A.* 2015, **71**, 3.
- S2 Sheldrick, G. M. Crystal Structure Refinement with SHELXL. *Acta Crystallogr. C.* 2015, **71**, 3.